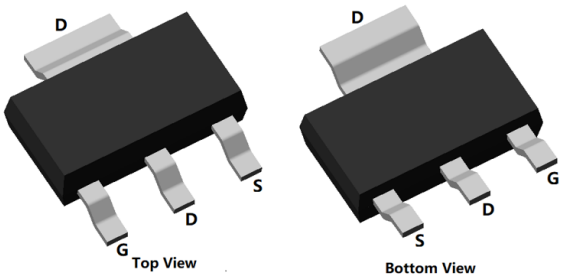
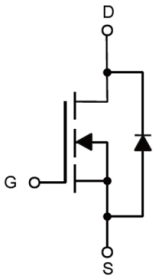
N-Channel Enhancement Mode Field Effect Transistor



SOT-223



Product Summary

- V_{DS} 100V
- I_D 4.0A
- $R_{DS(ON)}$(at V_{GS}= 10V) ＜110mohm
- $R_{DS(ON)}$(at V_{GS}= 4.5V) ＜120mohm

General Description

- Trench Power MV MOSFET technology
- Excellent package for heat dissipation
- High density cell design for low $R_{DS(ON)}$
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- DC-DC Converters
- Power management functions

■ Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-source Voltage		V_{DS}	100	V
Gate-source Voltage		V_{GS}	±20	V
Drain Current	T_A=25℃	I_D	4	A
	T_A=70℃		3.2	
Pulsed Drain Current [A]		I_{DM}	16	A
Total Power Dissipation @ T_A=25℃		P_D	2.5	W
Thermal Resistance Junction-to-Ambient [B]		$R_{\theta JA}$	50	℃/ W
Thermal Resistance Junction-to-Case		$R_{\theta JC}$	16	℃/ W
Junction and Storage Temperature Range		T_J ,T_{STG}	-55～+150	℃

■ Ordering Information (Example)

PREFERED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
M04N10A	F2	1004	2500	/	40000	13“ reel
			2500	5000	25000	13“ reel

■ Electrical Characteristics (T_J=25℃ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}= 0V, I_D=250μA	100			V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=100V,V_{GS}=0V			1	μA
Gate-Body Leakage Current	I_{GSS}	V_{GS}= ±20V, V_{DS}=0V			±100	nA
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}= V_{GS}, I_D=250μA	1.1	1.8	3.0	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	V_{GS}= 10V, I_D=4A		95	110	mΩ
		V_{GS}= 4.5V, I_D=3.2A		100	120	
Diode Forward Voltage	V_{SD}	I_S=4A,V_{GS}=0V		0.8	1.2	V
Maximum Body-Diode Continuous Current	I_S				4	A
Dynamic Parameters						
Input Capacitance	C_{iss}	V_{DS}=50V,V_{GS}=0V,f=1MHZ		1070		pF
Output Capacitance	C_{oss}			33		
Reverse Transfer Capacitance	C_{rss}			30		
Switching Parameters						
Total Gate Charge	Q_g	V_{GS}=10V,V_{DS}=50V,I_D=10A		26		nC
Gate-Source Charge	Q_{gs}			5.4		
Gate-Drain Charge	Q_{gd}			5.8		
Reverse Recovery Charge	Q_{rr}	I_F=10A, di/dt=100A/us		30.1		
Reverse Recovery Time	t_{rr}			40		ns
Turn-on Delay Time	$t_{D(on)}$	V_{GS}=10V,V_{DD}=50V,R_L=6.4Ω R_{GEN}=3Ω		7		
Turn-on Rise Time	t_r			24		
Turn-off Delay Time	$t_{D(off)}$			24		
Turn-off fall Time	t_f			31		

A. Pulse Test: Pulse Width≤300us,Duty cycle ≤2%.

B. $R_{\theta JA}$ is the sum of the junction-to-lead and lead-to-ambient thermal resistance, where the lead thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JL}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.

■ Typical Performance Characteristics

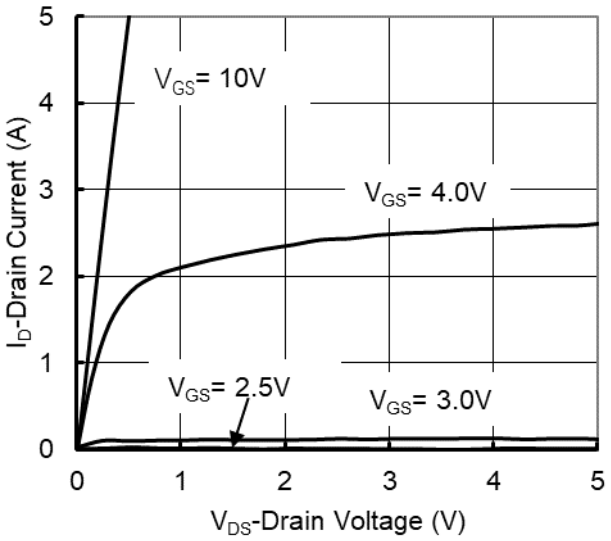


Figure 1. Output Characteristics

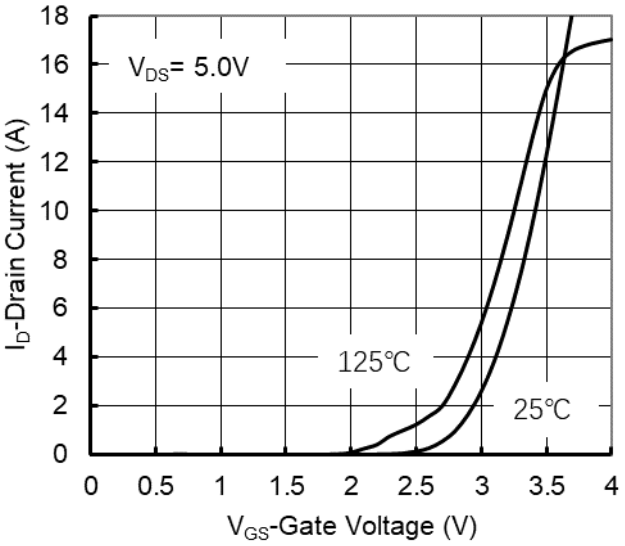


Figure 2. Transfer Characteristics

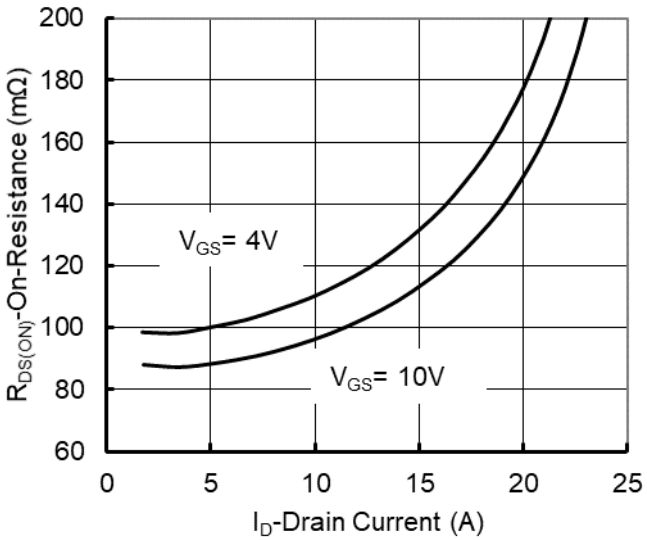


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

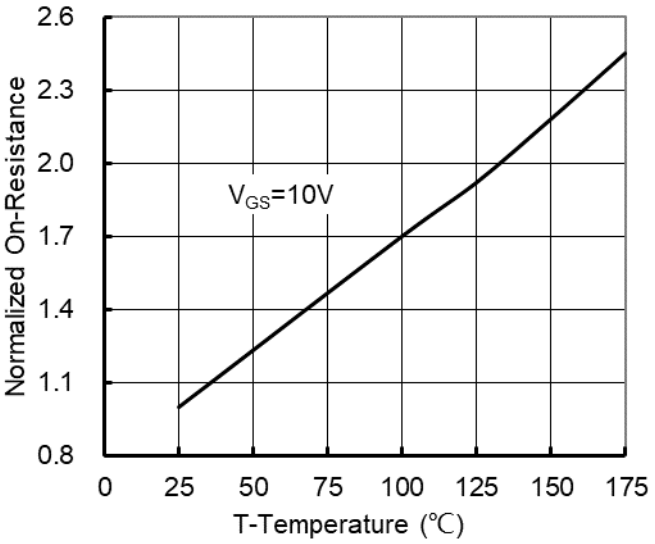


Figure 4. On-Resistance vs. Junction Temperature

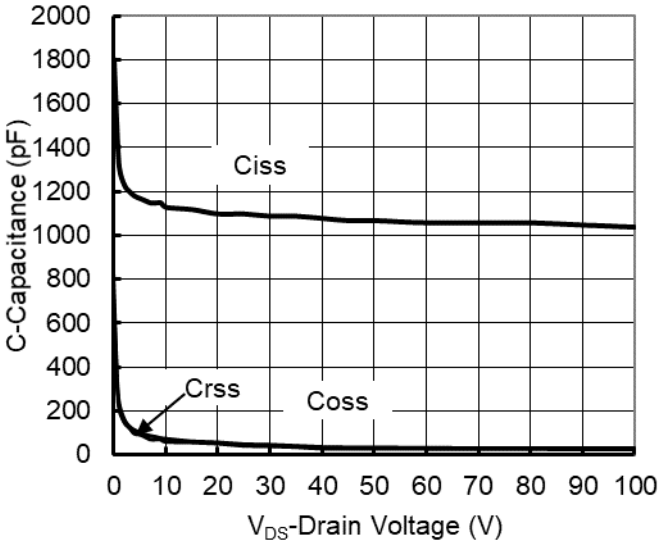


Figure 5. Capacitance Characteristics

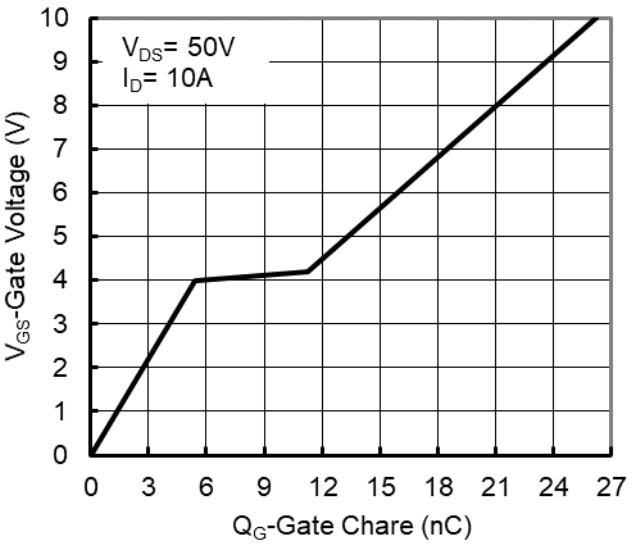


Figure 6. Gate Charge

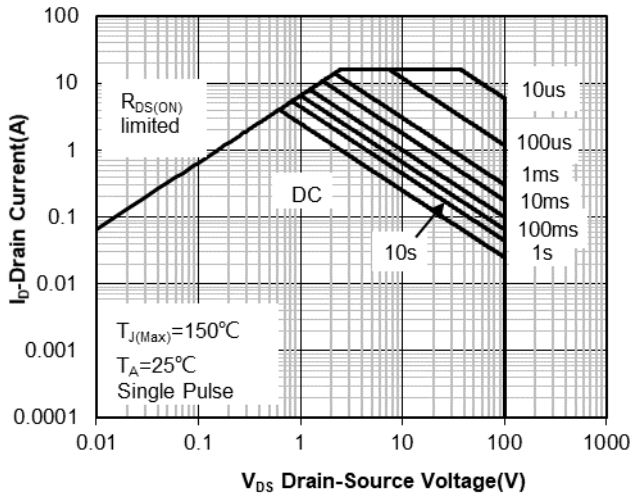


Figure 7. Safe Operation Area

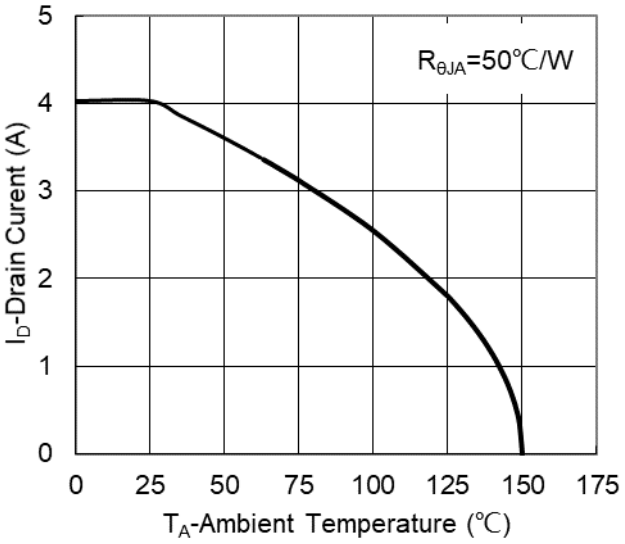


Figure 8. Maximum Continuous Drain Current vs Ambient Temperature

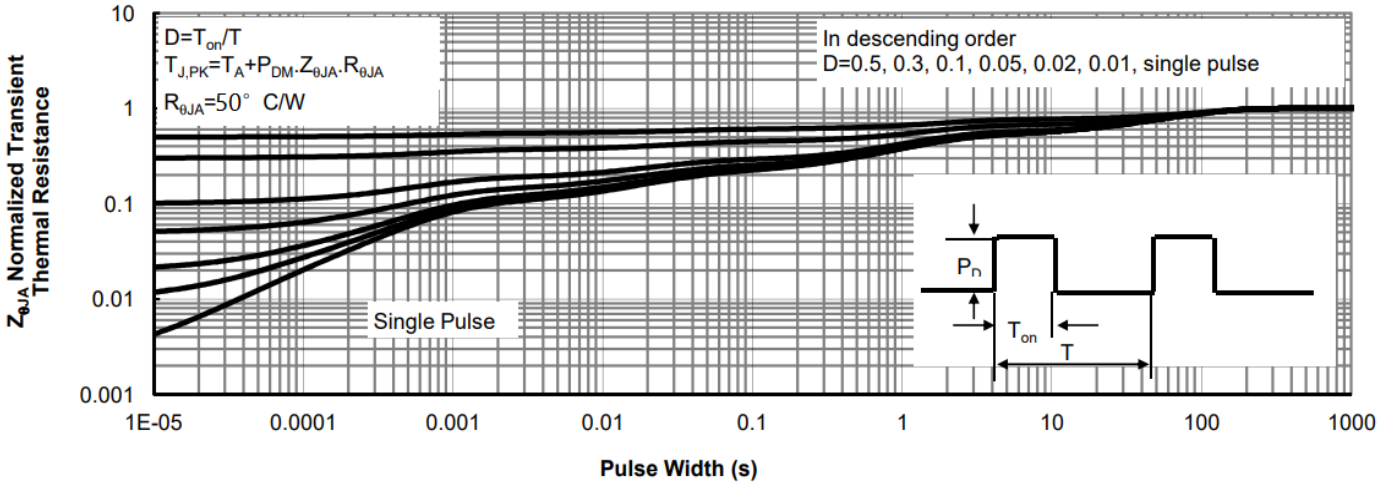
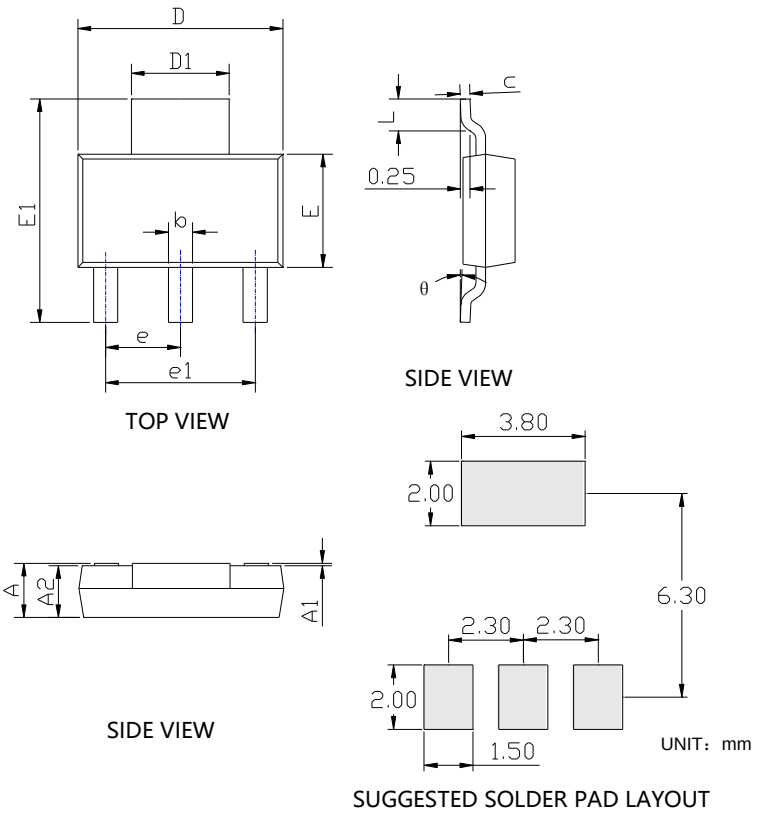


Figure 9. Normalized Maximum Transient Thermal Impedance

■ SOT-223 Package information

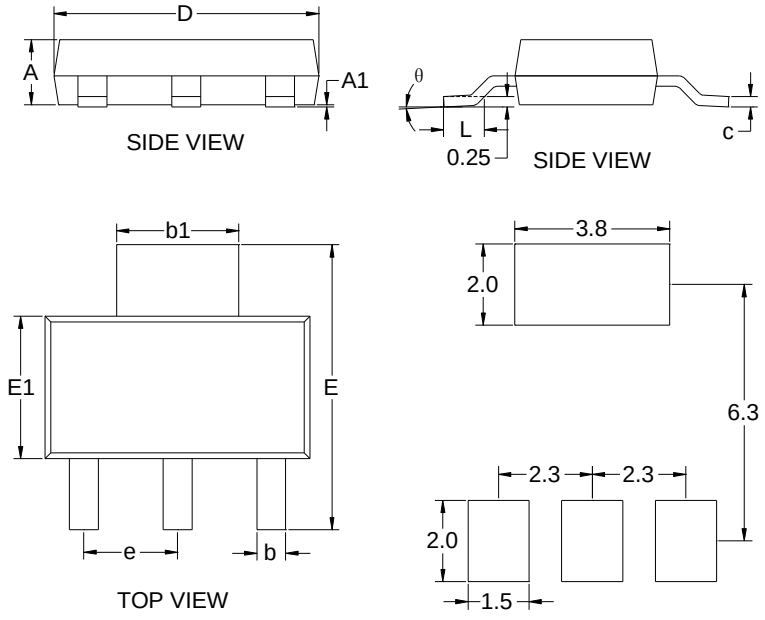
TYPE B:



DIMENSIONS				
SYMBOL	INCHES		Millimeter	
	MIN.	MAX.	MIN.	MAX.
A	0.060	0.071	1.520	1.800
A1	0.000	0.004	0.000	0.100
A2	0.059	0.067	1.500	1.700
b	0.026	0.032	0.660	0.820
c	0.010	0.014	0.250	0.350
D	0.244	0.252	6.200	6.400
D1	0.114	0.122	2.900	3.100
E	0.130	0.146	3.300	3.700
E1	0.269	0.278	6.830	7.070
e	0.091BSC		2.300BSC	
e1	0.177	0.185	4.500	4.700
L	0.035	0.045	0.900	1.150
θ	0°	10°	0°	10°

NOTE:
1.PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
2.TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
3.THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.

TYPE A：



DIMENSIONS				
DIM	INCHES		MM	
	MIN	MAX	MN	MAX
A	0.0591	0.0670	1.5000	1.7000
A1	0.0008	0.0039	0.0200	0.1000
b	0.0259	0.0330	0.6600	0.8400
b1	0.1140	0.1220	2.9000	3.1000
c	0.0090	0.0138	0.2300	0.3500
D	0.2480	0.2640	6.3000	6.7000
E	0.2637	0.2874	6.7000	7.3000
E1	0.1290	0.1460	3.3000	3.7000
e	0.0866	0.0945	2.2000	2.4000
L	0.0295	0.0492	0.7500	1.2500
θ	0°	10°	0°	10°

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